

## A. Single-Stage MOSFET Amplifiers

## 1. Introduction

-In this document, we will derive the expressions for the small-signal parameters ( $R_{in}$ ,  $R_{out}$ , and  $A_v$ ) for the 4 basic types of MOSFET single-stage amplifiers.

- Our focus will be on deriving results that can be *applied* to other single-stage amplifiers to obtain expressions and values for the key parameters of those amplifiers.



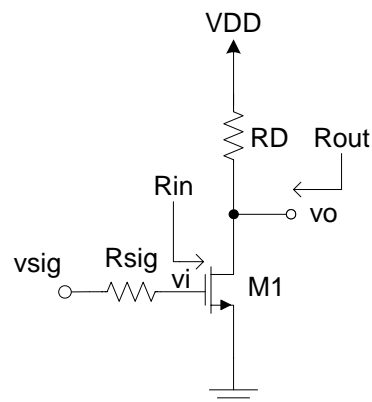
We will assume the following values for the DC and small-signal parameters for each transistor:

$$\begin{array}{llll} I_D := 1\text{mA} & g_m := 0.5 \frac{\text{mA}}{\text{V}} & R_{sig} := 2\text{k}\Omega & R_G := 2\text{k}\Omega \\ r_o := 500\text{k}\Omega & g_{mb} := 50 \frac{\mu\text{A}}{\text{V}} & R_D := 50\text{k}\Omega & R_S := 2\text{k}\Omega \end{array}$$

## General approach and notes:

- For each amplifier type, we will derive the entire expression for  $R_{in}$ ,  $R_{out}$ , and  $A_v$ .
- In practice, we will apply these results to specific amplifiers to determine desired expressions.
- In practice, the expressions can (and should) be simplified, if possible. Care should be taken to apply the proper simplifications.
- The biasing details of the amplifiers are not shown.

## 2. Common-Source (CS) Amplifier:



$R_{sig}$  is the total the total resistance seen by M1 looking out from the gate. In practice, it may be a "source resistor" or the output resistance of a "preceding stage".

$R_D$  is the total drain resistance, that is total the total resistance seen by M1 looking out from the drain. In practice, it may also contain a "load resistance",  $R_L$ , connected from "vo" to ground. Also  $R_L$  may be an actual load or the input resistance from a "subsequent stage".

$R_{sig}$  is *never* included in the calculation for  $R_{in}$ . If  $R_L$  is present, it is *never* included in the calculation of  $R_{out}$ . They are not considered part of the amplifier.

Figure 1. A common-source amplifier.  $v_i$  is the signal at the "input" terminal of the MOST.

a. The derivation of  $A_v$ ,  $R_{in}$ , and  $R_{out}$ :

The small-signal equivalent circuit is:

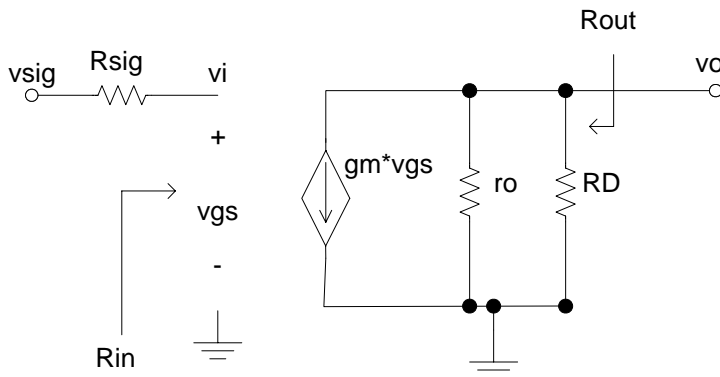


Figure 2. The small-signal equivalent circuit for the common-source amplifier

The expressions for the parameters can be determined by inspection:

$$R_{in} = \infty$$

$$R_{out} = r_o || R_D$$

$$\frac{v_o}{v_i} = -g_m \cdot (r_o || R_D)$$

$$A_v = \frac{v_o}{v_{sig}} = \frac{v_o}{v_i} = -g_m \cdot (r_o || R_D)$$

Note: Depending on the topology,  $v_o/v_{sig}$  is not always equal to  $v_o/v_i$ .



Substituting in the values for the small-signal parameters and finding the values for  $R_{in}$ ,  $R_{out}$ , and  $A_v$  gives:

$$R_{in} = \infty \quad R_{out} = 45.455 \text{ k}\Omega \quad A_v = -22.727 \frac{\text{V}}{\text{V}}$$

b. Simplifications (note there is no body effect in the amplifier):

(1) The condition for neglecting the effects of CLM is:  $r_o \gg R_D$

Then,  $R_{in} = \infty$      $R_{out} = R_D$      $A_v = -g_m \cdot R_D$

....1st order equations for the CS amplifier

3. Common-Source (CS/SR) with Source Resistor (source degeneration)

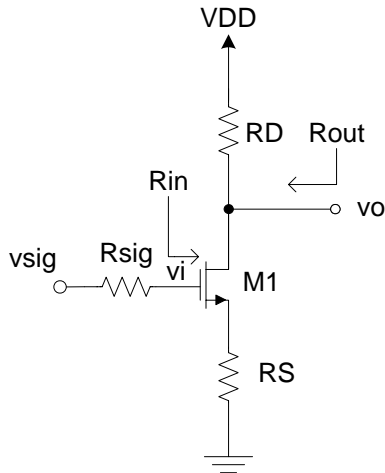


Figure 3. A common-source with source resistor amplifier

$R_{sig}$  is the total the total resistance seen by M1 looking out from the gate. In practice, it may be a "source resistor" or the output resistance of a "preceding stage".

$R_D$  is the total drain resistance, that is total the total resistance seen by M1 looking out from the drain. In practice, it may also contain a "load resistance",  $R_L$ , connected from "vo" to ground. Also  $R_L$  may be an actual load or the input resistance from a "subsequent stage".

$R_S$  is the total the total resistance seen by M1 looking out from the source.

$R_{sig}$  is *never* included in the calculation for  $R_{in}$ . If  $R_L$  is present, it is *never* included in the calculation of  $R_{out}$ . They are not considered part of the amplifier.

$v_i$  is the signal at the "input" terminal of the MOST.

The small-signal equivalent circuit is:

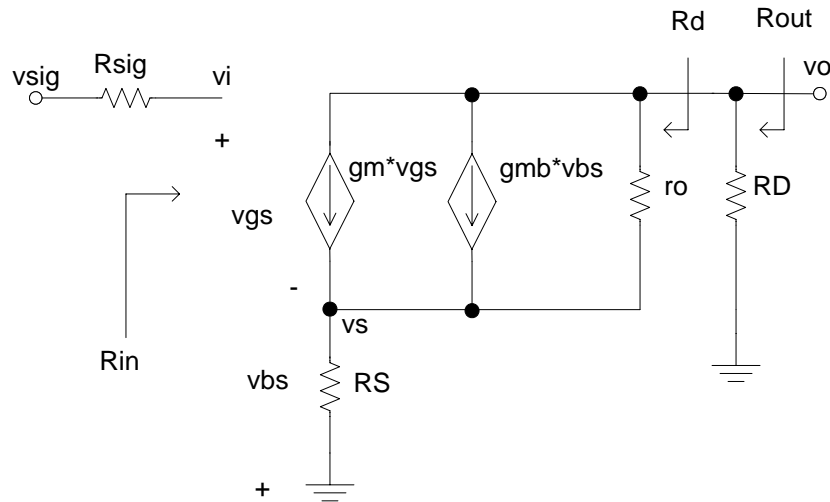


Figure 4. The small-signal equivalent circuit for the common-source with source resistor amplifier

- a.  $R_{in} = \infty$  by inspection.

b. Rout:

To find  $R_{out}$ , we will first find  $R_d$ , the small-signal resistance looking into the drain of M1. This situation comes up so often, it is worth generalizing this first, and then applying it to the CS/SR amplifier.

*Derivation for the small signal resistance seen looking into the drain of a MOSFET,  $R_d$ .*

A typical DC MOSFET circuit is shown as follows:

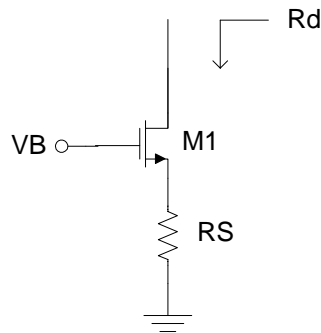
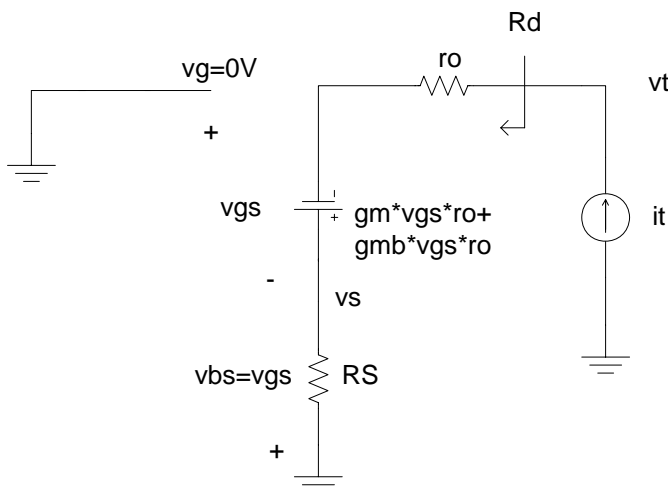


Figure 5. DC MOSFET circuit with  $R_d$ , the small-signal resistance looking into the drain, depicted.

The drain circuitry is not shown.  $R_S$  may be either a resistor, or some equivalent resistance seen looking *from* the source of M1 to ground, often realized by a single or multiple transistor circuit.

$V_B$  is a DC biasing voltage.

The small-signal equivalent circuit for determining  $R_d$  is:



We note from the small-signal equivalent circuit that our derivation may be used *whenever the gate is at signal ground.*

Figure 6. The small-signal equivalent circuit for determining  $R_d$ .

Since  $v_{bs} = v_{gs}$ , the current sources are combined. Then, the combination of the current sources and  $r_o$  are Thevenized, resulting in a voltage source in series with  $r_o$ .

By inspection:

$$v_t = i_t \cdot r_o - (g_m + g_{mb}) \cdot v_{gs} \cdot r_o + i_t \cdot R_S = i_t \cdot r_o - (g_m + g_{mb}) \cdot v_s \cdot r_o + i_t \cdot R_S$$

$$v_t = i_t \cdot r_o - (g_m + g_{mb}) \cdot (-i_t \cdot R_S) \cdot r_o + i_t \cdot R_S$$

Thus 
$$R_d = \frac{v_t}{i_t} = r_o + R_S + (g_m + g_{mb}) \cdot r_o \cdot R_S$$

Common simplifications: (IMPORTANT: This comes up often)

- 1)  $g_m \gg g_{mb}$
- 2)  $g_m \cdot r_o \gg 1$
- 3)  $R_S \approx r_o$  ( $R_S$  may be realized by a single transistor)

- 1)  $g_m \gg g_{mb}$

We note that often in practice,  $g_m \gg g_{mb}$  and can be determined by inspection. Recall that

$$g_{mb} = X \cdot g_m \text{ where } X \text{ is between } 0.1 \text{ and } 0.3.$$

- 2)  $g_m \cdot r_o \gg 1$

Note that 
$$g_m \cdot r_o = \frac{2 \cdot I_D}{V_{ov}} \cdot \frac{1}{\lambda \cdot I_D} = \frac{2}{V_{ov} \cdot \lambda}$$

For typical values of  $V_{ov}$  and  $\lambda$ ,  $V_{ov} := 250\text{mV}$  and  $\lambda := 0.01 \cdot V^{-1}$

$$g_m r_o := \frac{2}{V_{ov} \cdot \lambda} \quad g_m r_o = 800 \quad \dots \text{we see that this condition is generally true.}$$

Other forms of this approximation are: a)  $g_m \gg 1/r_o$  and b)  $r_o \gg 1/g_m$ .

- 3)  $R_S \approx r_o$ . This comes up often, but must be evaluated on a case-by-case basis.

Going back to the expression for  $R_d$ , and invoking simplifications 1, 2, and 3:

$$R_d = r_o + R_S + (g_m + g_{mb}) \cdot r_o \cdot R_S$$

$$R_d \approx (r_o + R_S + g_m \cdot r_o \cdot R_S) \quad g_m \gg g_{mb}$$

$$R_d \approx [r_o + R_S \cdot (1 + g_m \cdot r_o)]$$

$$R_d \approx (r_o + R_S \cdot g_m \cdot r_o) \quad g_m r_o \gg 1$$

$$R_d \approx [r_o \cdot (1 + g_m \cdot R_S)]$$

$$R_d \approx (g_m \cdot r_o \cdot R_S) \quad g_m r_o \gg 1 \text{ and remembering } R_S \approx r_o$$

Referring to Fig. (3) and Fig. (4) we see that the gate of M1 is at signal ground since  $v_{sig}$  is grounded for the  $R_{out}$  analysis and there is no voltage drop across  $R_{sig}$  since  $i_g=0$ . Thus, the results of the derivation of  $R_d$  apply, and we have:

Thus 
$$R_d = r_o + R_D + (g_m + g_{mb}) \cdot r_o \cdot R_S$$

and 
$$R_{out} = R_D \parallel [r_o + R_S + (g_m + g_{mb}) \cdot r_o \cdot R_S]$$

### c. $A_v$

To find  $A_v$ , we first find  $G_m$ . Then,  $A_v = -G_m \cdot R_{out}$ . The reason for this approach, is that it is the approach that uses the fewest and easiest calculations.

Remember, to find  $G_m$ , we short the output and find " $i_o$ " the current through the short. Then,  $G_m$  is equal to  $i_o/v_{sig}$ . It is conventional to define " $i_o$ " going "into" the amplifier.

Shorting the output shorts out  $R_D$ , thus, we may remove it from the circuit. The resulting small-signal equivalent circuit is:

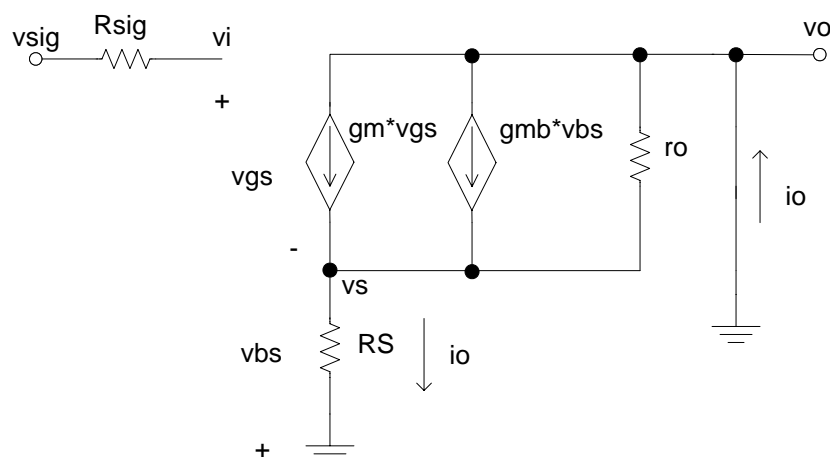


Figure 7. The small-signal equivalent circuit for determining  $A_v$  for the common-source with source resistor amplifier.

Note that "io" must flow through RS. The current through RS is determined by recognizing that since both ro and RS are grounded, and in parallel, the current from the current sources divides between the two resistors in accordance to the current divider rule.

Thus

$$i_o = \frac{r_o}{r_o + R_S} \cdot (g_m \cdot v_{gs} + g_{mb} \cdot v_{bs})$$

Since  $v_{bs} = -i_o \cdot R_S$  and  $v_{gs} = v_i - v_s = v_i - i_o \cdot R_S$

$$i_o = \frac{r_o}{r_o + R_S} \cdot [g_m \cdot (v_i - i_o \cdot R_S) + g_{mb} \cdot (-i_o \cdot R_S)]$$

Solving for io and then io/vi, results in

$$\frac{i_o}{v_i} = G_m = \frac{g_m \cdot r_o}{r_o + R_S + (g_m + g_{mb}) \cdot r_o \cdot R_S} = \frac{i_o}{v_{sig}}$$

Thus,

$$A_v = -G_m \cdot R_{out} = -\frac{g_m \cdot r_o}{r_o + R_S + (g_m + g_{mb}) \cdot r_o \cdot R_S} \cdot [[R_D \parallel [r_o + R_S + (g_m + g_{mb}) \cdot r_o \cdot R_S]]]$$

$$A_v = -\frac{g_m \cdot r_o}{r_o + R_S + (g_m + g_{mb}) \cdot r_o \cdot R_S} \cdot \frac{R_D \cdot [r_o + R_S + (g_m + g_{mb}) \cdot r_o \cdot R_S]}{R_D + r_o + R_S + (g_m + g_{mb}) \cdot r_o \cdot R_S}$$

$$A_v = -\frac{g_m \cdot r_o \cdot R_D}{R_D + r_o + R_S + (g_m + g_{mb}) \cdot r_o \cdot R_S} = \frac{-g_m \cdot R_D}{1 + \left( g_m + g_{mb} + \frac{1}{r_o} \right) \cdot R_S + \frac{R_D}{r_o}}$$

In summary, for the common-source with source resistor:

$$R_{in} = \infty$$

$$R_{out} = R_D \parallel [r_o + R_S + (g_m + g_{mb}) \cdot r_o \cdot R_S]$$

$$A_v = \frac{-g_m \cdot R_D}{1 + \left( g_m + g_{mb} + \frac{1}{r_o} \right) \cdot R_S + \frac{R_D}{r_o}}$$

Substituting in our numbers gives:



$$R_{in} = \infty \quad R_{out} = 45.455 \text{ k}\Omega \quad A_v = -11.882 \frac{V}{V}$$

#### d. Simplifications:

i) The conditions for neglecting the body effect are:  $g_m \gg g_{mb}$

Then  $R_{in} = \infty$

$$R_{out} = R_D \parallel (r_o + R_S + g_m \cdot r_o \cdot R_S)$$

$$A_v = \frac{-g_m \cdot R_D}{1 + \left(g_m + \frac{1}{r_o}\right) \cdot R_S + \frac{R_D}{r_o}}$$

ii) A "primary" condition for neglecting CLM is (assuming the body effect is neglected)  $r_o \gg 1/g_m$ ,  $R_D$

Then  $R_{in} = \infty$

$$R_{out} = R_D$$

....1st order equations for the CS/SR amplifier

$$A_v = \frac{-g_m \cdot R_D}{1 + g_m \cdot R_S}$$

iii) It is also possible to neglect CLM but include the Body Effect.



4. The Common Gate (CG) Amplifier

$R_D$  is the total drain resistance, that is total the total resistance seen by M1 looking out from the drain. In practice, it may also contain a "load resistance",  $R_L$ , connected from "vo" to ground. Also  $R_L$  may be an actual load or the input resistance from a "subsequent stage".

$R_{sig}$  is the total the total resistance seen by M1 looking out from the source. It may be part of the amplifier or it may be part of the driving source vsig. It may also consist of a component that is part of the amplifier and one from the source. It may also represent the output resistance from a "preceding stage".

$R_{sig}$  is *not* included in the  $R_{in}$  calculation, unless it is part of the amplifier. If  $R_L$  is applied, it is *never* included in the  $R_{out}$  calculation, since it is ususally considered to be not part of the amplifier.

For this example, we assume that it is not part of the amplifier, but is part of the "driving source resistance".

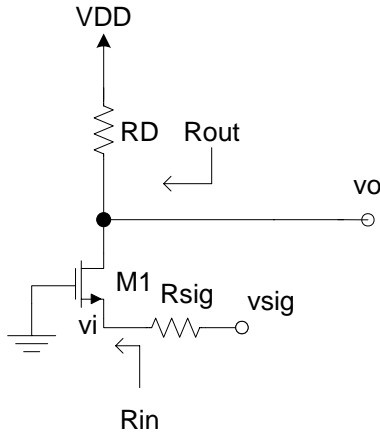


Figure 8. A common-gate amplifier

$v_i$  is the signal at the "input" terminal of the MOST.

a.  $R_{in}$  and  $v_o/v_i$ :

Due to the relatively small input impedance of the common-gate amplifier, in order to find the gain of the circuit we first find  $v_o/v_i$  and then  $R_{in}$ . Then,

$$\frac{v_o}{v_{sig}} = \frac{v_i}{v_{sig}} \cdot \frac{v_o}{v_i} = \frac{R_{in}}{R_{in} + R_S} \cdot \frac{v_o}{v_i}$$

The small-signal equivalent circuit is:

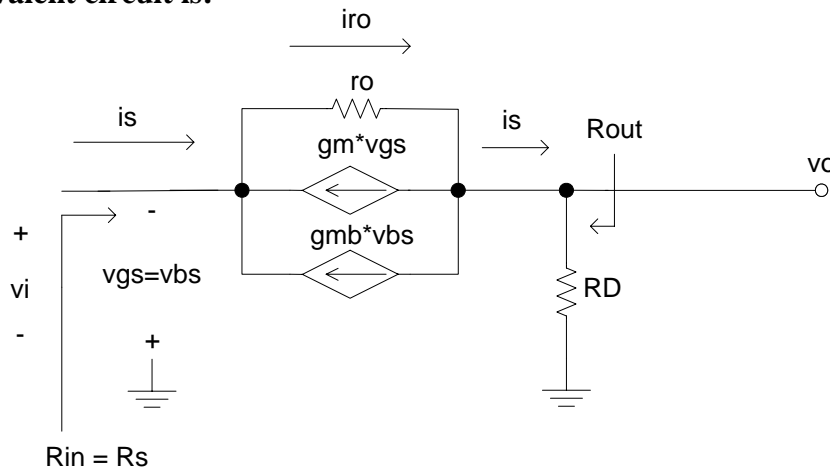


Figure 9. Small-signal equivalent circuit for the common-gate amplifier (wo  $R_{sig}$  and  $v_{sig}$ )

To determine the input resistance for the amplifier, we need to find the small-signal resistance seen looking into the source,  $R_s$ . This situation comes up so often, it is worth generalizing this first, and then applying it to the CG amplifier.

*Derivation for the small signal resistance seen looking into the source of a MOSFET,  $R_s$ .*

A typical DC MOSFET circuit is shown as follows:

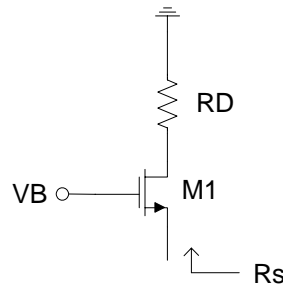
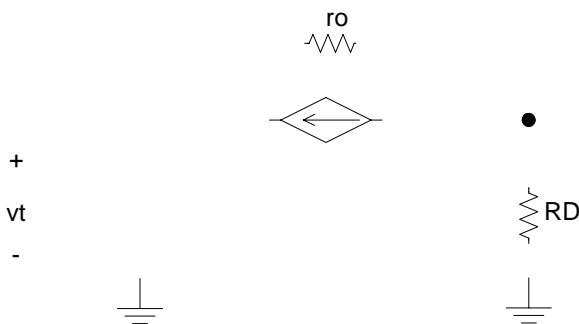


Figure 10. DC MOSFET circuit with  $R_s$ , the small-signal resistance looking into the drain, depicted.

The drain circuitry is not shown.  $R_D$  may be either a resistor, or some equivalent resistance seen looking *from* the drain of M1 to ground, often realized by a single or multiple transistor circuit.

$V_B$  is a DC biasing voltage.

The small-signal equivalent circuit for determining  $R_s$  is:



We note from the small-signal equivalent circuit that our derivation may be used *whenever the gate is at signal ground*.

Figure 11. Small-signal equivalent circuit used to determine  $R_s$ .

We see that

$$v_t = i_{ro} \cdot r_o + i_t \cdot R_D = (i_t + g_m \cdot -v_t + g_{mb} \cdot -v_t) \cdot r_o + i_t \cdot R_D$$

Solving for  $v_s$ , find:

$$v_t = \frac{R_D + r_o}{1 + (g_m + g_{mb}) \cdot r_o} \cdot i_t$$

Thus 
$$R_s = \frac{v_s}{i_s} = \frac{R_D + r_o}{1 + (g_m + g_{mb}) \cdot r_o} = \frac{1 + \frac{R_D}{r_o}}{g_m + g_{mb} + \frac{1}{r_o}}$$

$$R_s = (1/g_m \parallel 1/g_{mb} \parallel r_o) \cdot \left(1 + \frac{R_D}{r_o}\right)$$

If  $g_m \gg g_{mb}$  and  $g_m \cdot r_o \gg 1$

$$R_s = 1/g_m \cdot \left(1 + \frac{R_D}{r_o}\right)$$

If  $r_o \gg R_D$

$$R_s = 1/g_m \quad \text{This occurs often!}$$

Applying the results of  $R_s$  to the CG amplifier,

Thus

$$R_{in} = \frac{v_i}{i_s} = (1/g_m \parallel 1/g_{mb} \parallel r_o) \cdot \left(1 + \frac{R_D}{r_o}\right)$$

Now, referring to Fig. (9),

$$v_o = i_s \cdot R_D = R_D \cdot \frac{v_i}{R_{in}} = \frac{R_D}{(1/g_m \parallel 1/g_{mb} \parallel r_o) \cdot \left(1 + \frac{R_D}{r_o}\right)} \cdot v_i = \left(g_m + g_{mb} + \frac{1}{r_o}\right) \cdot (r_o \parallel R_D) \cdot v_i$$

So

$$\frac{v_o}{v_i} = \left( g_m + g_{mb} + \frac{1}{r_o} \right) \cdot r_o \parallel R_D$$

And

$$A_v = \frac{R_{in}}{R_{in} + R_S} \cdot \left[ \left( g_m + g_{mb} + \frac{1}{r_o} \right) \cdot r_o \parallel R_D \right]$$

**b. Rout:**

**Rout is the small-signal equivalent circuit seen looking into the drain,  $R_d$ , in parallel with  $R_D$ .**

**Thus,**  $R_{out} = R_D \parallel [r_o + R_{sig} + (g_m + g_{mb}) \cdot r_o \cdot R_{sig}]$

**In summary, for the common-gate amplifier:**

$$R_{in} = (1/g_m \parallel 1/g_{mb} \parallel r_o) \cdot \left( 1 + \frac{R_D}{r_o} \right)$$

$$R_{out} = R_D \parallel [r_o + R_{sig} + (g_m + g_{mb}) \cdot r_o \cdot R_{sig}]$$

$$\frac{v_o}{v_i} = \left( g_m + g_{mb} + \frac{1}{r_o} \right) \cdot r_o \parallel R_D$$

$$A_v = \frac{v_i}{v_{sig}} \frac{v_o}{v_i} = \frac{R_{in}}{R_{in} + R_S} \cdot \left[ \left( g_m + g_{mb} + \frac{1}{r_o} \right) \cdot r_o \parallel R_D \right]$$



**Plugging in our numbers:**

$$R_{in} = 1.993 \text{ k}\Omega$$

$$R_{out} = 47.731 \text{ k}\Omega$$

$$A_v = 12.523 \frac{V}{V}$$

c. Simplifications

The main simplifications are:

To neglected the body effect:  $g_m \gg g_{mb}$

To neglect the effects of CLM:  $r_o \gg 1/g_m$  and  $r_o \gg R_D$ .

Clearly, there are many variations of this. For example, in the expression for  $R_{in}$ , we may have  $r_o \gg 1/g_m$ , but not  $r_o \gg R_D$ .

Applying these simplifications, yields:

$$R_{in} = \frac{1}{g_m}$$

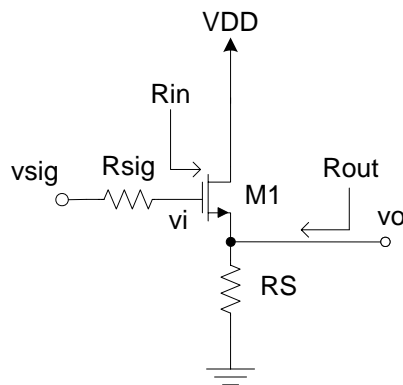
$$R_{out} = R_D$$

$$\frac{v_o}{v_i} = g_m \cdot R_D$$

....1st order equations for the CG amplifier.

$$A_v = \frac{v_i}{v_{sig}} \frac{v_o}{v_i} = \frac{R_{in}}{R_{in} + R_S} \cdot g_m \cdot R_D = \frac{\frac{1}{g_m}}{\frac{1}{g_m} + R_S} \cdot g_m \cdot R_D = \frac{g_m \cdot R_D}{1 + g_m \cdot R_S}$$

5. Common-Drain (CD) Amplifier (Source Follower (SF))



$R_{sig}$  is the total the total resistance seen by M1 looking out from the gate. In practice, it may be a "source resistor" or the output resistance of a "preceding stage".

$R_S$  is the total the total resistance seen by M1 looking out from the source. In practice, it may also contain a "load resistance",  $R_L$ , connected from " $v_o$ " to ground.  $R_L$  may be an actual load or the input resistance from a "subsequent stage".

$R_{sig}$  is *never* included in the  $R_{in}$  calculation, unless it is part of the amplifier. If  $R_L$  is applied, it is *never* included in the  $R_{out}$  calculation, since it is usually considered to be not part of the amplifier.

$v_i$  is the signal at the "input" terminal of the MOST.

Figure 12. A common-drain amplifier

a.  $v_o/v_{sig}$  and  $R_{in}$ :

$R_{sig}$  is neglected since the current flowing through it is 0A. The small-signal equivalent circuit is:

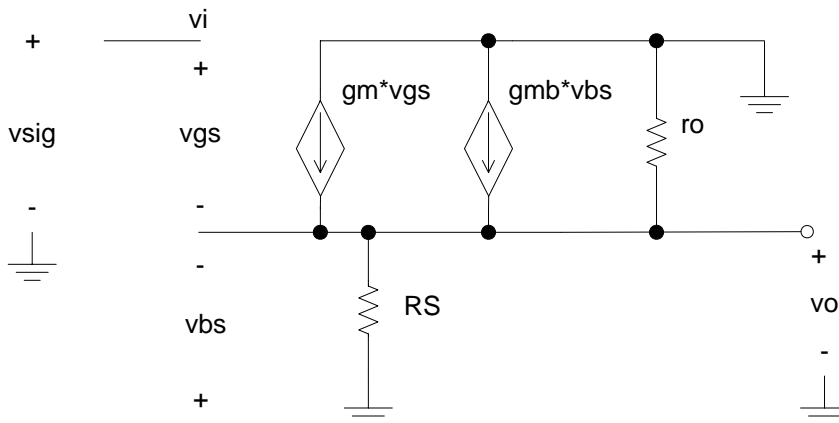


Figure 13. Small-signal equivalent circuit for the Common drain amplifier

We need to simplify this circuit. Note that the controlling voltage ( $v_{bs}$ ) of the source  $g_{mb} \cdot v_{bs}$  is for all practical purposes, directly across itself.

Consider the following situation:

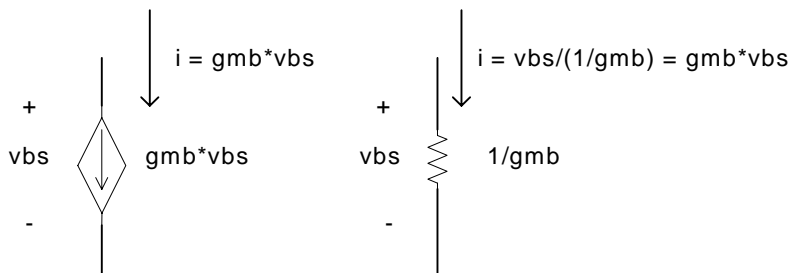


Figure 14. Simplifications for the common-drain amplifier

Applying a voltage of  $v_{bs}$  across this controlled source results in a current of  $g_{mb} \cdot v_{bs}$ . Applying a voltage of  $v_{bs}$  across a resistor of value  $1/g_{mb}$  also results in a current of  $g_{mb} \cdot v_{bs}$ . Thus, the circuits are equivalent and the voltage controlled current source may be modeled as a resistor when the controlling voltage is applied across the device with the polarity shown. This comes up often and is worth making a note about.

The small-signal equivalent circuit may be simplified to:

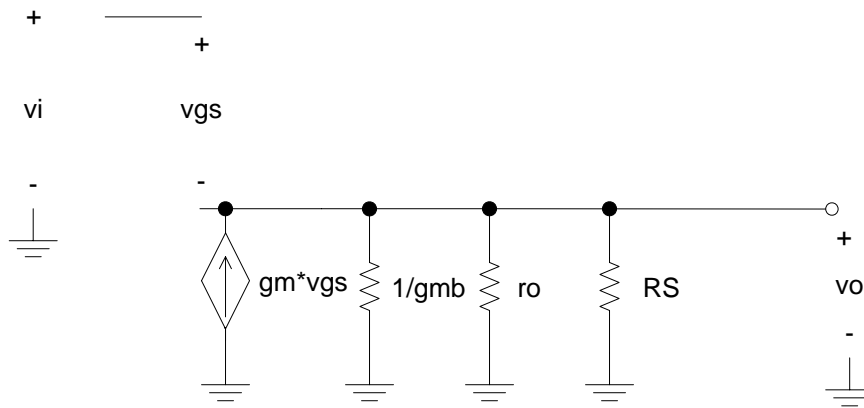


Figure 15. Simplified small-signal equivalent circuit for the common-drain amplifier

Let

$$R_x = 1/g_{mb} || r_o || R_S$$

Then

$$v_o = g_m \cdot v_{gs} \cdot R_x = g_m \cdot (v_i - v_o) \cdot R_x$$

Solving for  $v_o/v_g$ , find

$$\frac{v_o}{v_i} = \frac{v_o}{v_i} = \frac{g_m \cdot (1/g_{mb} || r_o || R_S)}{1 + g_m \cdot (1/g_{mb} || r_o || R_S)} = A_v = \frac{g_m \cdot R_S}{1 + \left( g_m + g_{mb} + \frac{1}{r_o} \right) \cdot R_S}$$

After some algebra.

By inspection.

$$R_{in} = \infty$$

b. Rout:

Rout is  $R_s$  in parallel with  $R_S$ .

$$R_s = (1/g_m || 1/g_{mb} || r_o) \cdot \left( 1 + \frac{0}{r_o} \right) \quad \text{since } R_D = 0\Omega$$

$$R_s = (1/g_m || 1/g_{mb} || r_o)$$

Thus,  $R_{out} = 1/g_m || 1/g_{mb} || r_o || R_S$

In summary:  $R_{in} = \infty$        $R_{out} = 1/g_m || 1/g_{mb} || r_o || R_S$

$$A_v = \frac{g_m \cdot R_S}{1 + \left( g_m + g_{mb} + \frac{1}{r_o} \right) \cdot R_S}$$



Plugging in our numbers, find:

$$R_{in} = \infty \quad R_{out} = 950.57 \Omega \quad A_v = 0.475 \frac{V}{V}$$

c. Simplifications:

i. To neglect the body effect  $1/g_{mb} \gg R_S$ , or  $g_{mb} \ll 1/R_S$

ii. To neglect the effects of CLM  $r_o \gg R_S$

Of course, there are several other variations. This yields:

$$R_{in} = \infty \quad R_{out} = 1/g_m || R_S \quad A_v = \frac{g_m \cdot R_S}{1 + g_m \cdot R_S}$$

....1st order equations for the CD amplifier.

Often,  $g_m R_S \gg 1$ , and  $A_v = 1 V/V$ .

## 6. Applying the results

When applying the results, some general guidelines are:

1. Identify the amplifier type.
2. Apply the desired expression. Simplify when possible.

7. Remember, you should be able to *derive* these results as well as *apply* these results.